

4MBI400VG-060R-50

IGBT Modules

IGBT MODULE (V series)

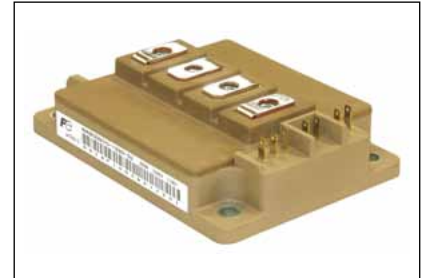
600V / 400A / IGBT, RB-IGBT 4 in one package

■ Features

- Higher Efficiency
- Optimized A (T-type) -3 level circuit
- Low inductance module structure
- Featuring Reverse Blocking IGBT (RB-IGBT)

■ Applications

- Inverter for Motor Drive
- Uninterruptible Power Supply
- Power conditioner



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

| Items | | Symbols | Conditions | | Maximum ratings | Units | |
|-----------------------------|---------------------------------------|------------------|-----------------------|----------------------|----------------------|-------|---|
| T1, T2 | Collector-Emitter voltage | V _{CEs} | | | 600 | V | |
| | Gate-Emitter voltage | V _{GEs} | | | ±20 | V | |
| | Collector current | IGBT | I _c | Continuous | T _c =80°C | 400 | A |
| | | | I _{cp} | 1ms | T _c =80°C | 800 | |
| | | FWD | -I _c | | | 400 | |
| | | | -I _{c pulse} | 1ms | | 800 | |
| Collector power dissipation | P _c | 1 device | | 1135 | W | | |
| T3, T4 | Collector-Emitter voltage | V _{CEs} | | | 600 | V | |
| | Gate-Emitter voltage | V _{GEs} | | | ±20 | V | |
| | Collector current | I _c | Continuous | T _c =80°C | 400 | A | |
| | | I _{cp} | 1ms | T _c =80°C | 800 | | |
| Collector power dissipation | P _c | 1 device | | 1560 | W | | |
| Junction temperature | | T _j | | | 150 | °C | |
| Case temperature | | T _c | | | 125 | | |
| Storage temperature | | T _{stg} | | | -40 ~ +125 | | |
| Isolation voltage | between terminal and copper base (*1) | V _{iso} | AC : 1min. | | 2500 | VAC | |
| Screw torque | Mounting (*2) | - | M5 or M6 | | 3.5 | N m | |
| | Terminals (*3) | - | M5 | | 3.5 | | |

Note *1: All terminals should be connected together during the test.

Note *2: Recommendable value : 2.5-3.5 Nm (M5 or M6)

Note *3: Recommendable value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at T_j = 25°C unless otherwise specified)

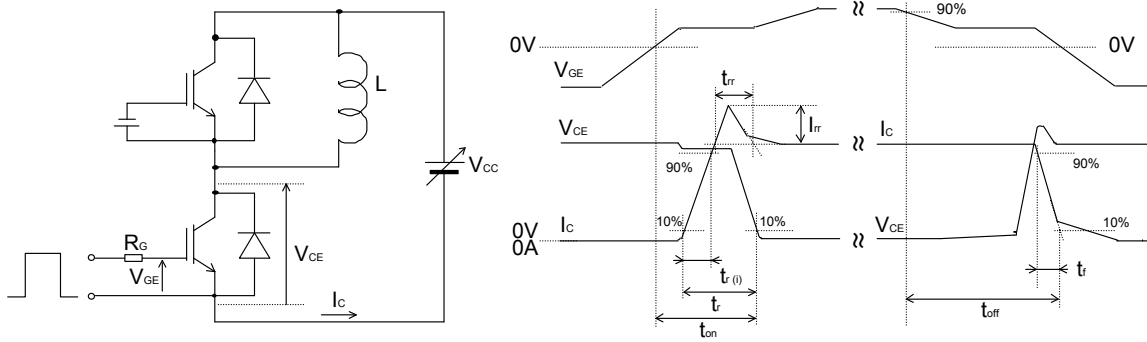
| Items | Symbols | Conditions | Characteristics | | | Units | | |
|-----------------------|--------------------------------------|---|--|------------------------|------|-------|------|---|
| | | | min. | typ. | max. | | | |
| T1, T2 | Zero gate voltage collector current | I _{CES} | V _{GE} = 0V, V _{CE} = 600V | - | - | 2.0 | mA | |
| | Gate-Emitter leakage current | I _{GES} | V _{CE} = 0V, V _{GE} = ±20V | - | - | 400 | nA | |
| | Gate-Emitter threshold voltage | V _{GE(th)} | V _{CE} = 20V, I _c = 400mA | 6.2 | 6.7 | 7.2 | V | |
| | Collector-Emitter saturation voltage | V _{CE(sat)} (chip) | V _{GE} = 15V I _c = 400A | T _j = 25°C | - | 1.60 | 1.85 | V |
| | | | | T _j = 125°C | - | 1.90 | - | |
| | | V _{CE(sat)} (terminal) | V _{GE} = 15V I _c = 400A | T _j = 25°C | - | 1.79 | 2.10 | |
| | | | | T _j = 125°C | - | 2.09 | - | |
| | Input capacitance | C _{ies} | V _{CE} = 10V, V _{GE} = 0V, f = 1MHz | - | 27 | - | nF | |
| | Turn-on time | t _{on} | SW mode : A V _{CC} = 400V I _c = 400A V _{GE} = ±15V R _G = +10/-39Ω L _S = 80nH | - | 0.95 | 1.90 | μs | |
| | | t _r | | - | 0.65 | 1.30 | | |
| | | t _{r(f)} | | - | 0.30 | - | | |
| Turn-off time | t _{off} | R _G = +10/-39Ω L _S = 80nH | - | 3.20 | 6.40 | μs | | |
| | t _f | | - | 0.20 | 0.50 | | | |
| Forward on voltage | V _F (chip) | I _F = 400A | T _j = 25°C | - | 1.60 | 1.85 | V | |
| | | | T _j = 125°C | - | 1.50 | - | | |
| | V _F (terminal) | I _F = 400A | T _j = 25°C | - | 1.72 | 2.05 | | |
| | | | T _j = 125°C | - | 1.62 | - | | |
| Reverse recovery time | t _{rr} | SW mode : A V _{CC} = 400V I _F = 400A V _{GE} = ±15V R _G = +10/-39Ω | - | - | 0.35 | μs | | |
| T3, T4 | Zero gate voltage collector current | I _{CES} | V _{GE} = 0V, V _{CE} = 600V | - | - | 4.0 | mA | |
| | Gate-Emitter leakage current | I _{GES} | V _{CE} = 0V, V _{GE} = ±20V | - | - | 800 | nA | |
| | Gate-Emitter threshold voltage | V _{GE(th)} | V _{CE} = 20V, I _c = 400mA | 5.5 | 6.5 | 7.5 | V | |
| | Collector-Emitter saturation voltage | V _{CE(sat)} (chip) | V _{GE} = 15V I _c = 400A | T _j = 25°C | - | 2.45 | 2.80 | V |
| | | | | T _j = 125°C | - | 2.60 | - | |
| | | V _{CE(sat)} (terminal) | V _{GE} = 15V I _c = 400A | T _j = 25°C | - | 2.67 | 3.10 | |
| | | | | T _j = 125°C | - | 2.82 | - | |
| | Input capacitance | C _{ies} | V _{CE} = 10V, V _{GE} = 0V, f = 1MHz | - | 26 | - | nF | |
| | Turn-on time | t _{on} | SW mode : B V _{CC} = 200V I _c = 400A V _{GE} = ±15V R _G = +2.2/-39Ω L _S = 54nH | - | 0.35 | 0.70 | μs | |
| | | t _r | | - | 0.25 | 0.50 | | |
| | | t _{r(f)} | | - | 0.15 | - | | |
| Turn-off time | t _{off} | R _G = +2.2/-39Ω L _S = 54nH | - | 1.75 | 3.50 | μs | | |
| | t _f | | - | 0.15 | 0.35 | | | |
| Reverse recovery time | t _{rr} | SW mode : C V _{CC} = 200V I _c = 400A V _{GE} = ±15V R _G = +10/-39Ω | - | - | 0.35 | μs | | |
| Internal inductance | L | P-N | - | 40 | - | nH | | |
| | | P-M | - | 33 | - | | | |
| | | M-N | - | 33 | - | | | |

● Thermal resistance characteristics

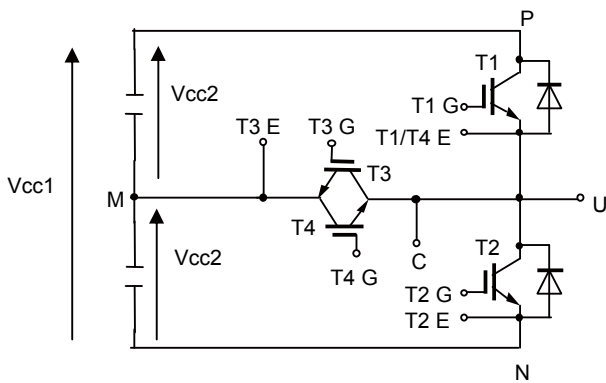
| Items | Symbols | Conditions | Characteristics | | | Units |
|---|----------------------|----------------|-----------------|-------|------|-------|
| | | | min. | typ. | max. | |
| Thermal resistance (1device) | R _{th(j-c)} | T1, T2 IGBT | - | - | 0.11 | °C/W |
| | | T1, T2 FWD | - | - | 0.22 | |
| | | T3, T4 RB-IGBT | - | - | 0.08 | |
| Contact thermal resistance (1device) (*4) | R _{th(c-f)} | T1, T2 | - | 0.025 | - | °C/W |
| | | T3, T4 | - | 0.013 | - | |

Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound (thermal conductivity = 1W/m·K).

■ Definitions of switching time



Definitions of switching mode



| SW mode | Load L | T1 | T2 | T3 | T4 |
|---------|--------|-----------|-----------|-----------|-----------|
| A | U-N | SW | OFF | OFF | OFF |
| | P-U | OFF | SW | OFF | OFF |
| B | P-U | OFF | OFF | SW | ON |
| | U-N | OFF | OFF | ON | SW |
| C | M-U | SW | OFF | OFF | ON |
| | M-U | OFF | SW | ON | OFF |

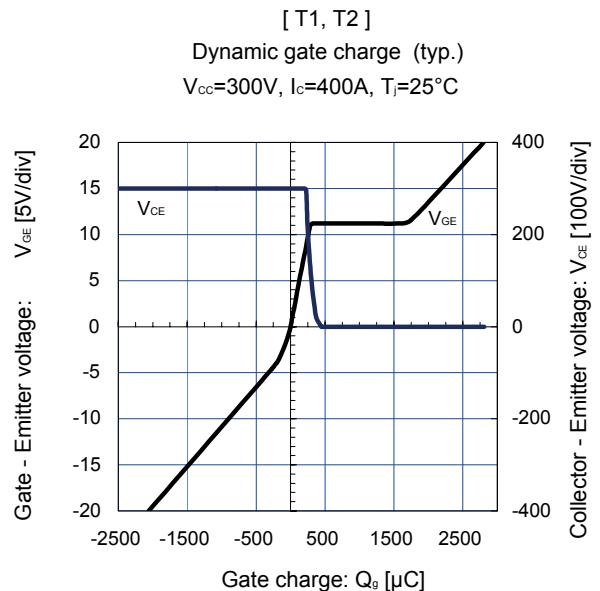
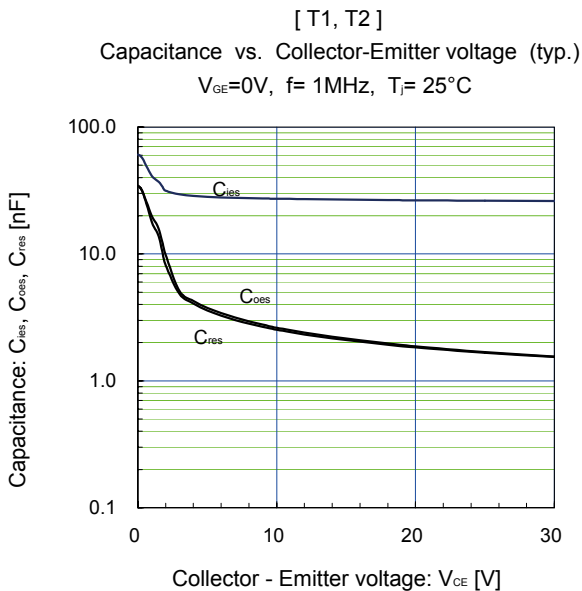
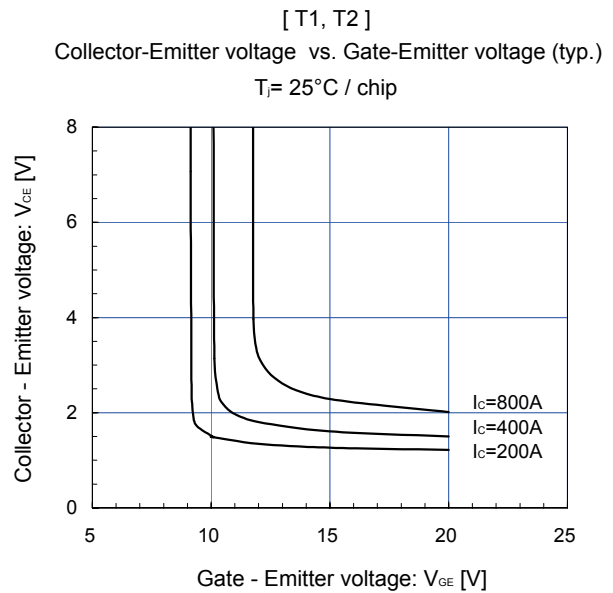
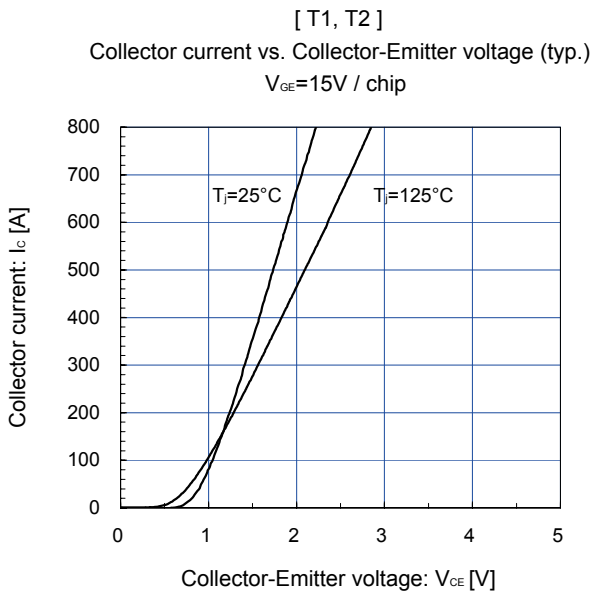
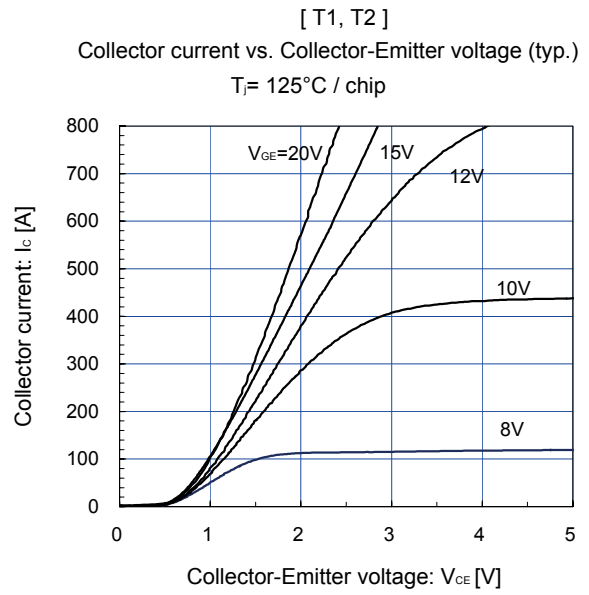
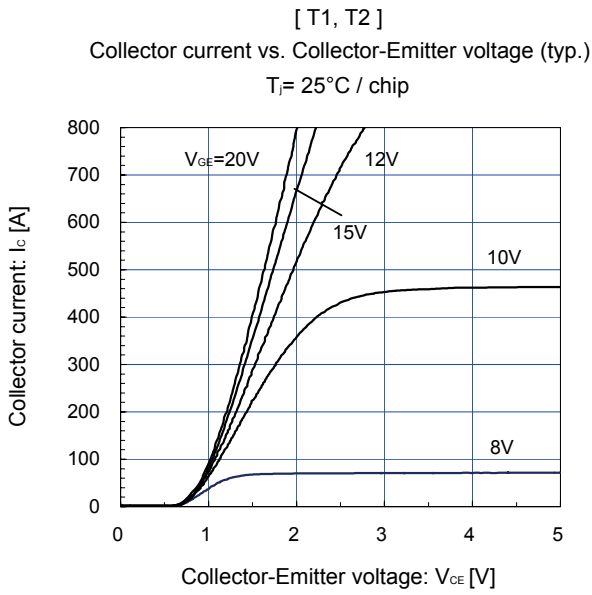
SW: Connect to drive circuit and input gate signal

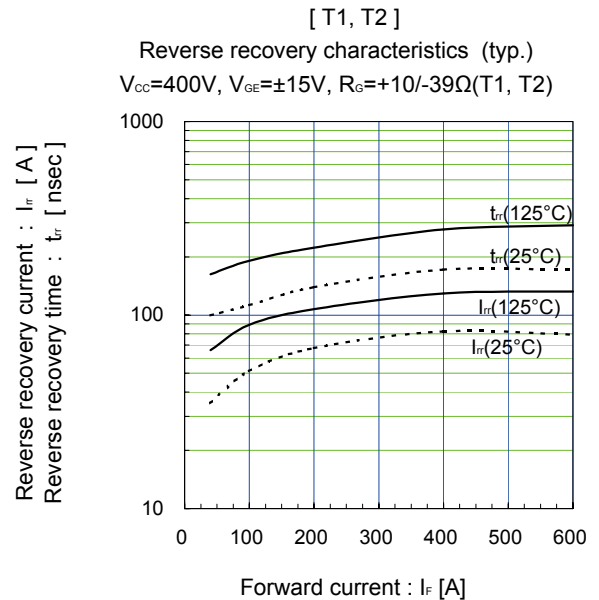
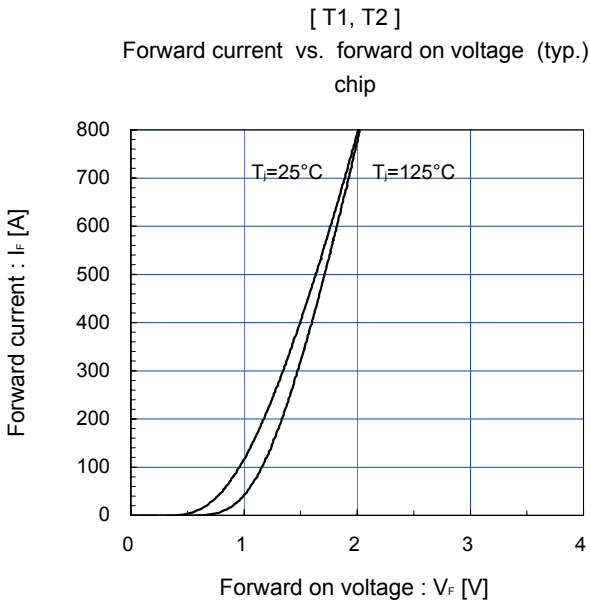
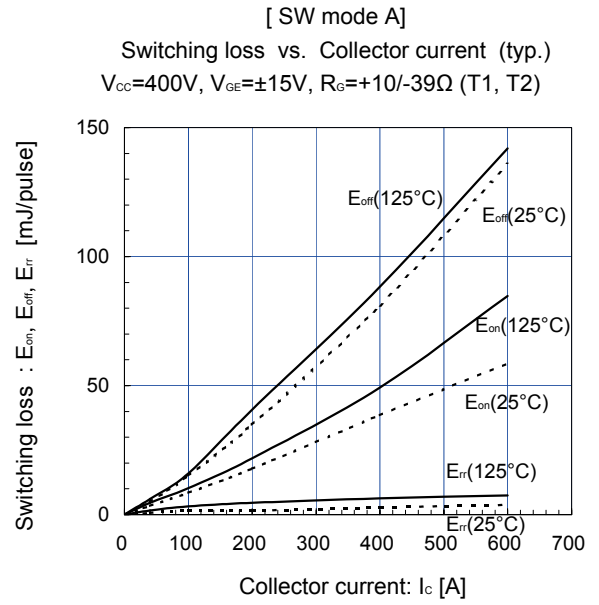
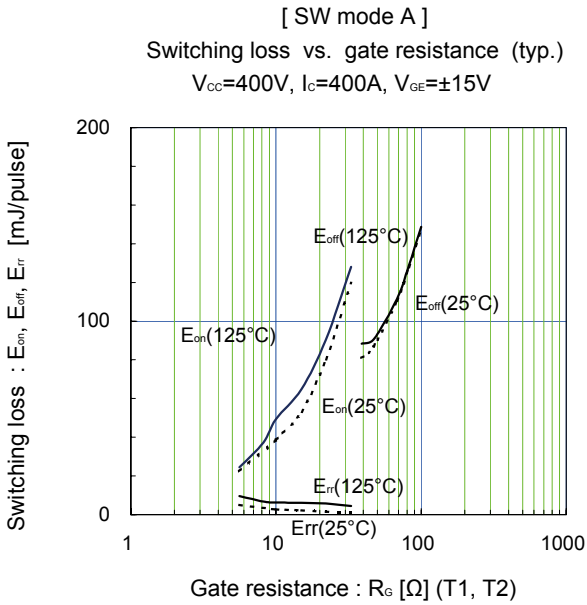
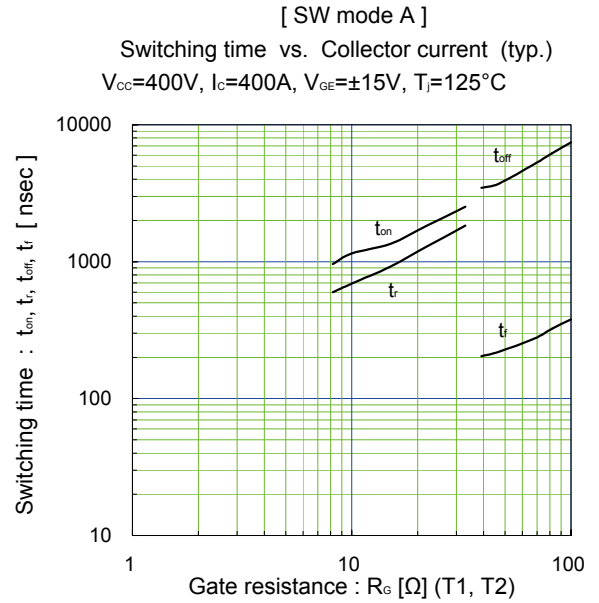
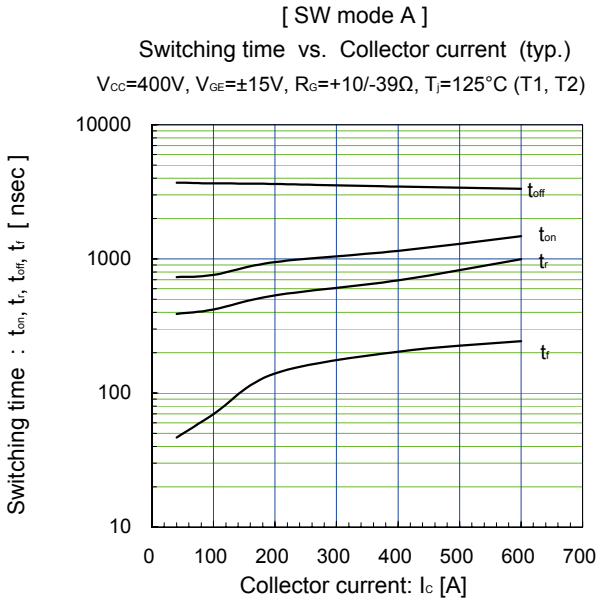
ON: Bias voltage of gate +15V

OFF: Reverse bias voltage of gate -15V

Vcc2=Vcc1/2

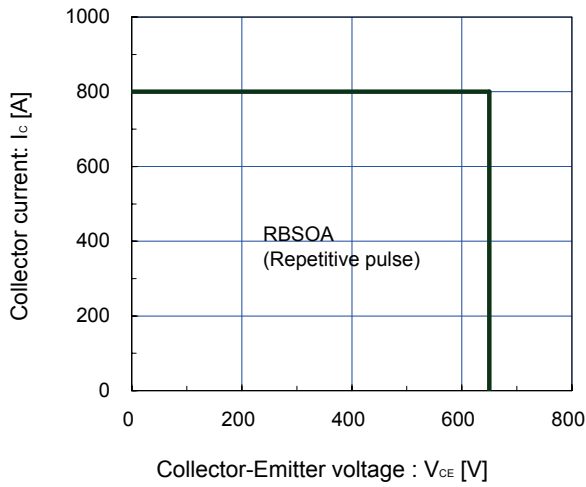
■ Characteristics (Representative)





Reverse bias safe operating area (max.)

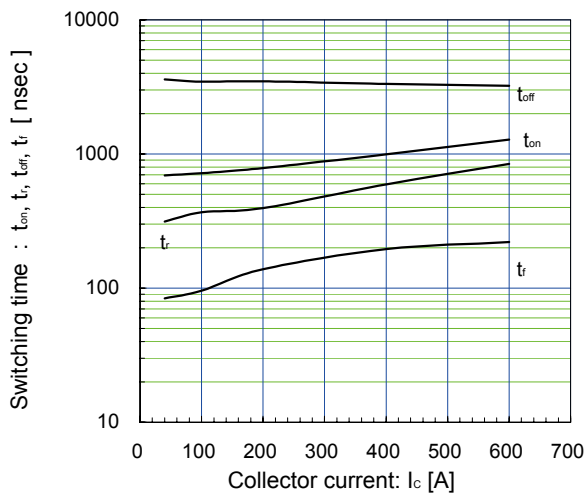
$V_{GE}=15V, -V_{GE} \leq 15V, R_G \geq +10 / -39\Omega, T_J \leq 125^\circ C (T1, T2)$
 T1, T2 (Terminal)



[SW mode C]

Switching time vs. Collector current (typ.)

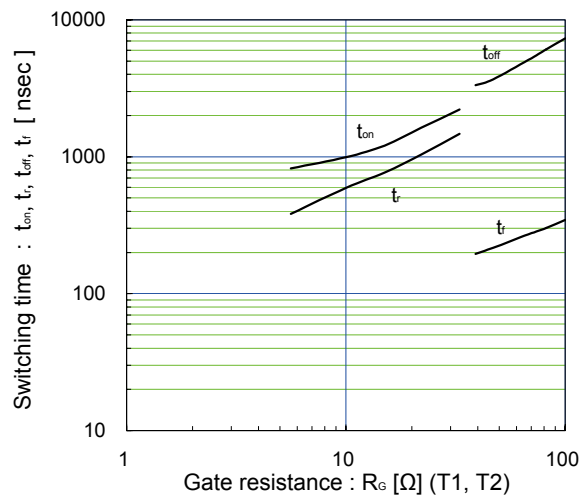
$V_{CC}=200V, V_{GE}=\pm 15V, R_G=\pm 10/-39\Omega, T_J=125^\circ C (T1, T2)$



[SW mode C]

Switching time vs. Collector current (typ.)

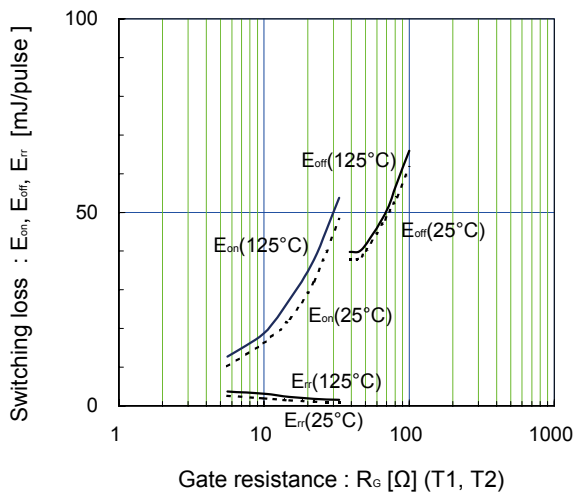
$V_{CC}=200V, I_c=400A, V_{GE}=\pm 15V, T_J=125^\circ C$



[SW mode C]

Switching loss vs. gate resistance (typ.)

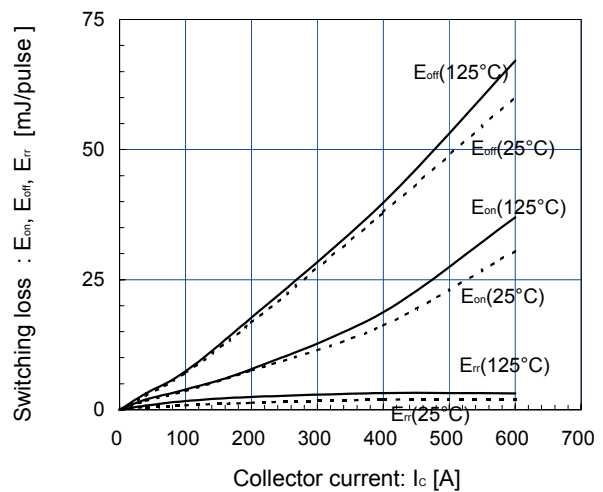
$V_{CC}=200V, I_c=400A, V_{GE}=\pm 15V$

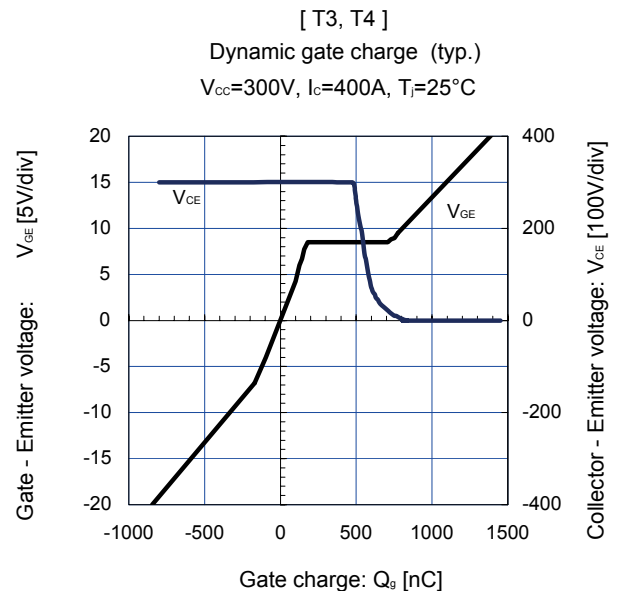
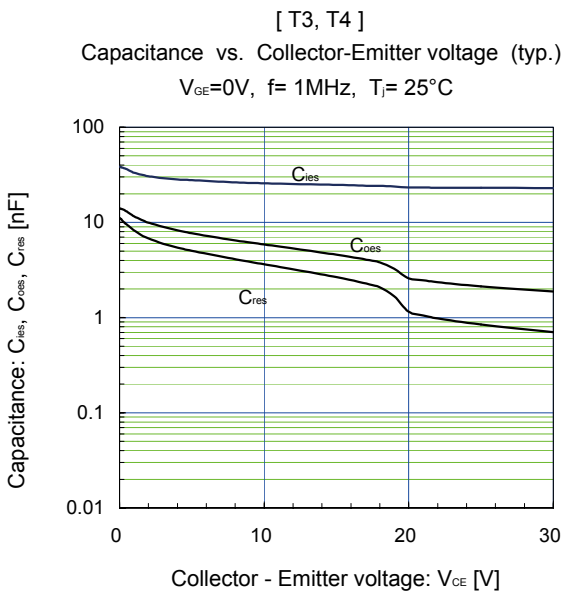
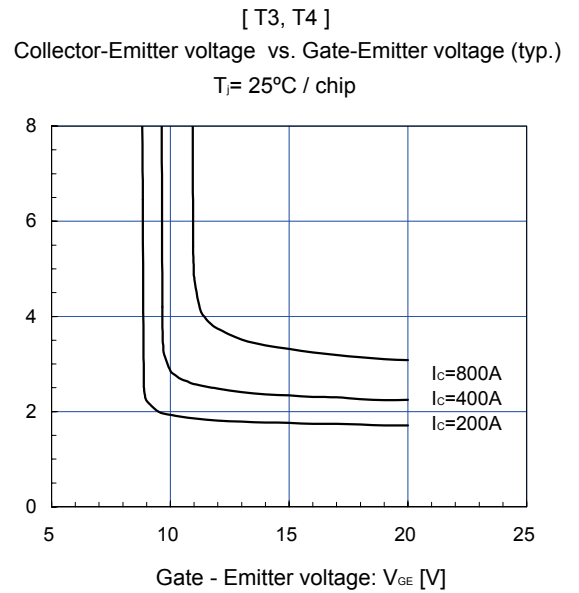
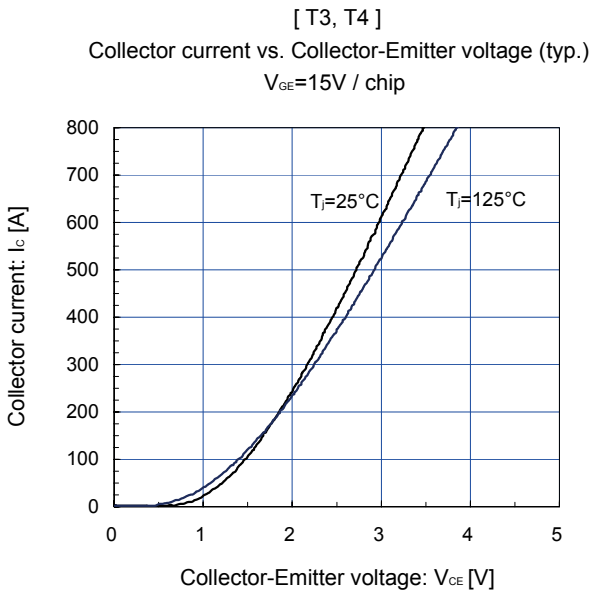
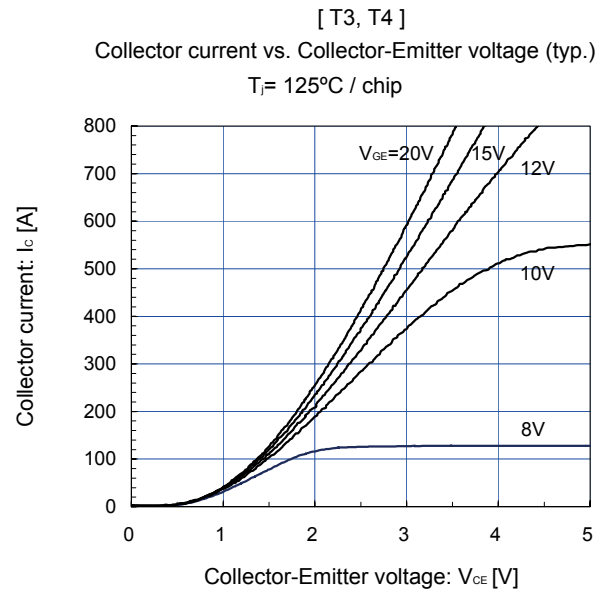
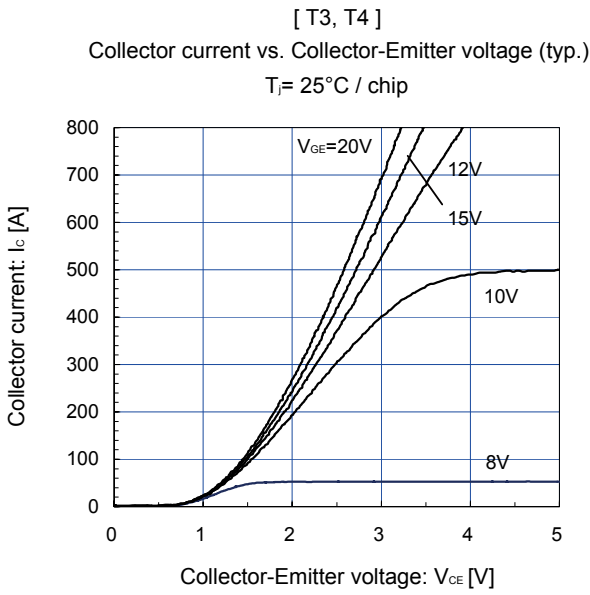


[SW mode C]

Switching loss vs. Collector current (typ.)

$V_{CC}=200V, V_{GE}=\pm 15V, R_G=\pm 10/-39\Omega (T1, T2)$

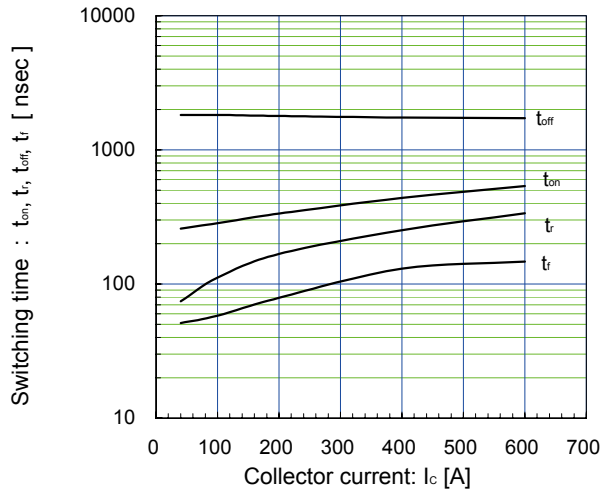




[SW mode B]

Switching time vs. Collector current (typ.)

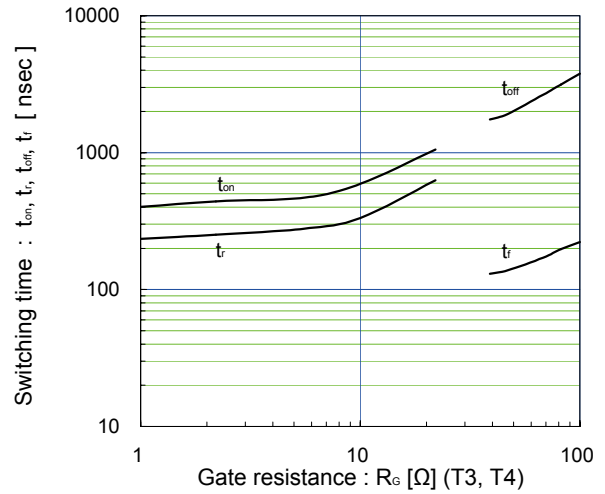
$V_{CC}=200V, V_{GE}=\pm 15V, R_G=+2.2/-39\Omega, T_J=125^\circ C$ (T3, T4)



[SW mode B]

Switching time vs. Collector current (typ.)

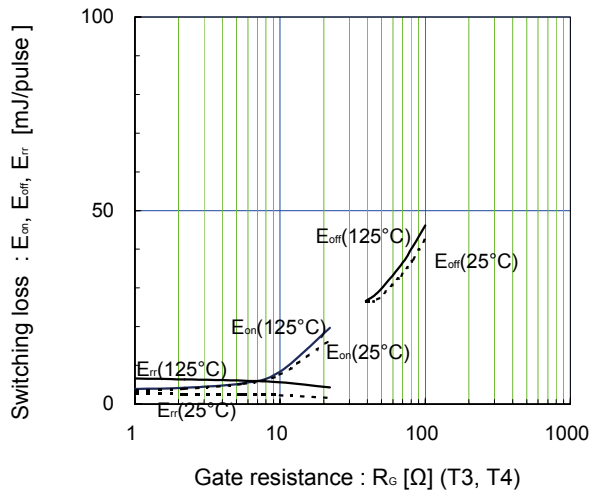
$V_{CC}=200V, I_C=400A, V_{GE}=\pm 15V, T_J=125^\circ C$



[SW mode B]

Switching loss vs. gate resistance (typ.)

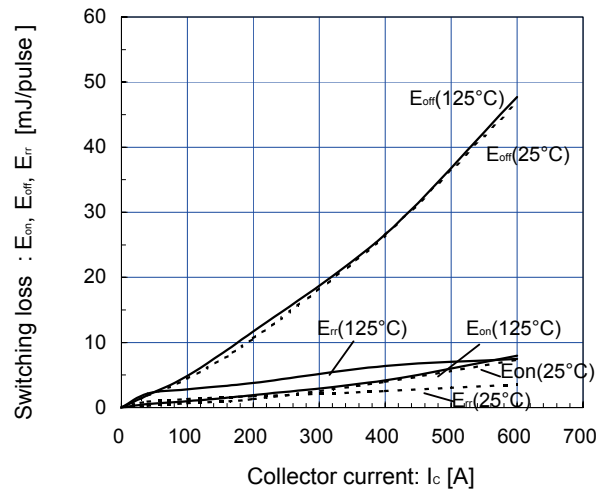
$V_{CC}=200V, I_C=400A, V_{GE}=\pm 15V$



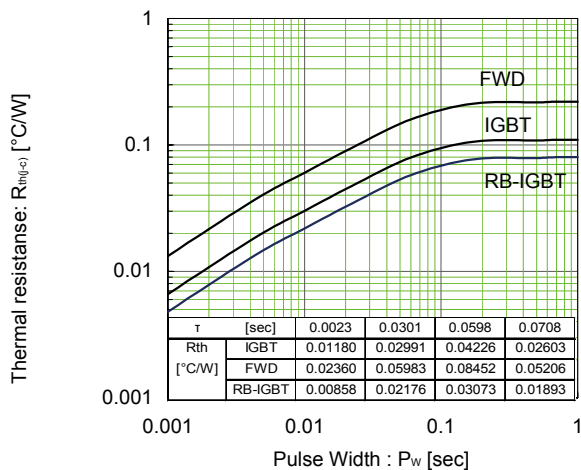
[SW mode B]

Switching loss vs. Collector current (typ.)

$V_{CC}=200V, V_{GE}=\pm 15V, R_G=+2.2/-39\Omega$ (T3, T4)



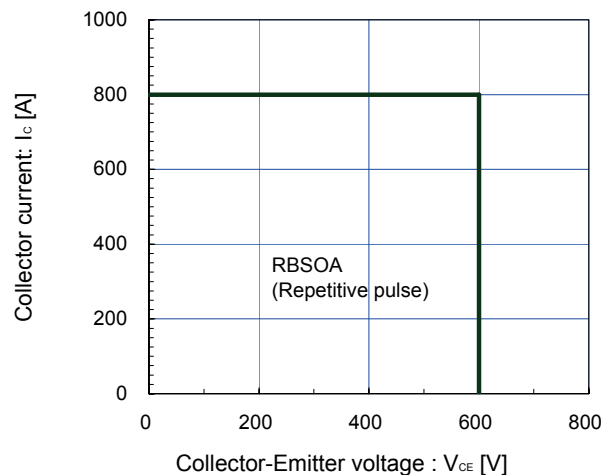
Transient Thermal Resistance (max.)



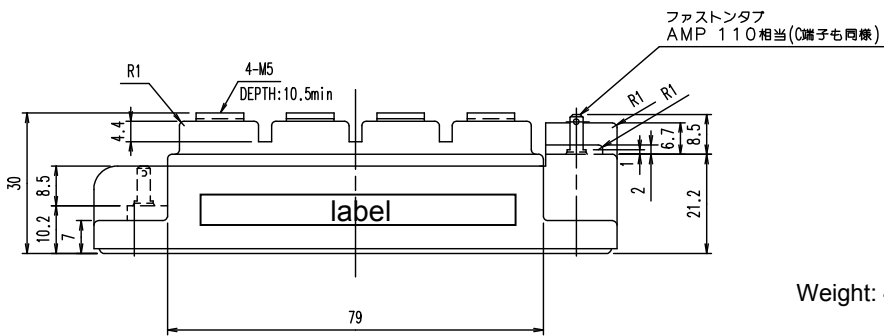
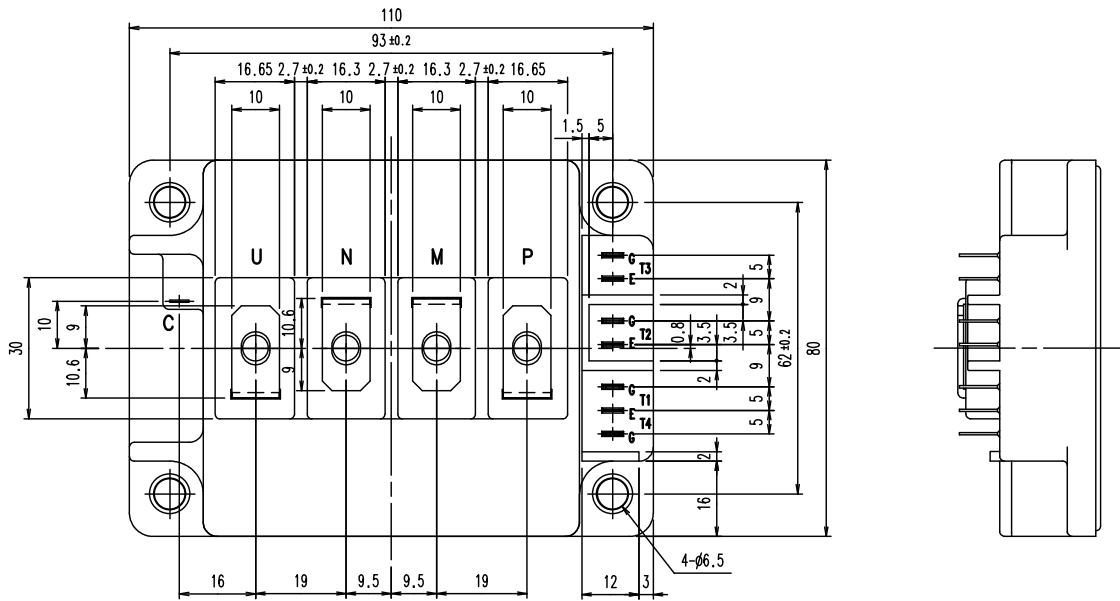
Reverse bias safe operating area (max.)

$V_{GE}=15V, -V_{GE} \leq 15V, R_G \geq +2.2 / -39\Omega, T_J \leq 125^\circ C$ (T3, T4)

T3, T4 (Terminal)

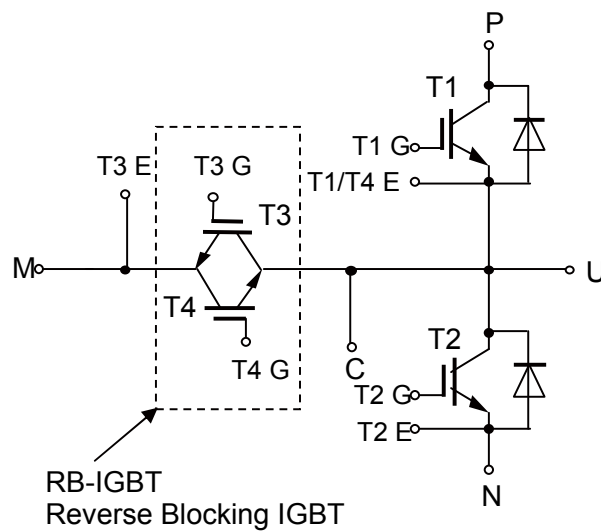


■ Outline Drawings, mm



Weight: 460g (typ.)

■ Equivalent Circuit Schematic



WARNING

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